

SOT-723 Plastic-Encapsulate Diodes

SWITCHING DIODE

FEATURES

- Ultra Small Surface Mounting Type
- Ultra High Speed Switching Applications
- High Reliability
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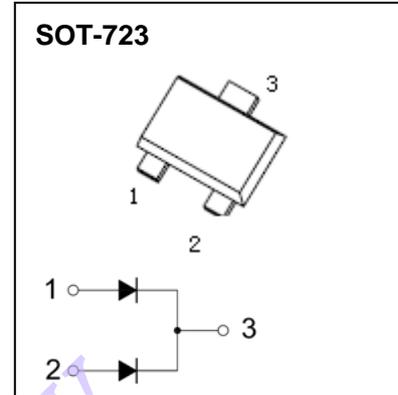
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MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{RRM}	Peak Reverse Voltage	80	V
V _{RWM}	Working Peak Reverse Voltage	80	V
V _{R(RMS)}	RMS Reverse Voltage	56	V
I _O	Continuous Forward Current	100	mA
I _{FM}	Peak Forward Current	300	mA
I _{FSM}	Non-Repetitive Peak Forward Surge Current (t=1μs)	4	A
P _D	Power Dissipation	150	mW
R _{θJA}	Thermal Resistance from Junction to Ambient	833	°C/W
T _j	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise specified)

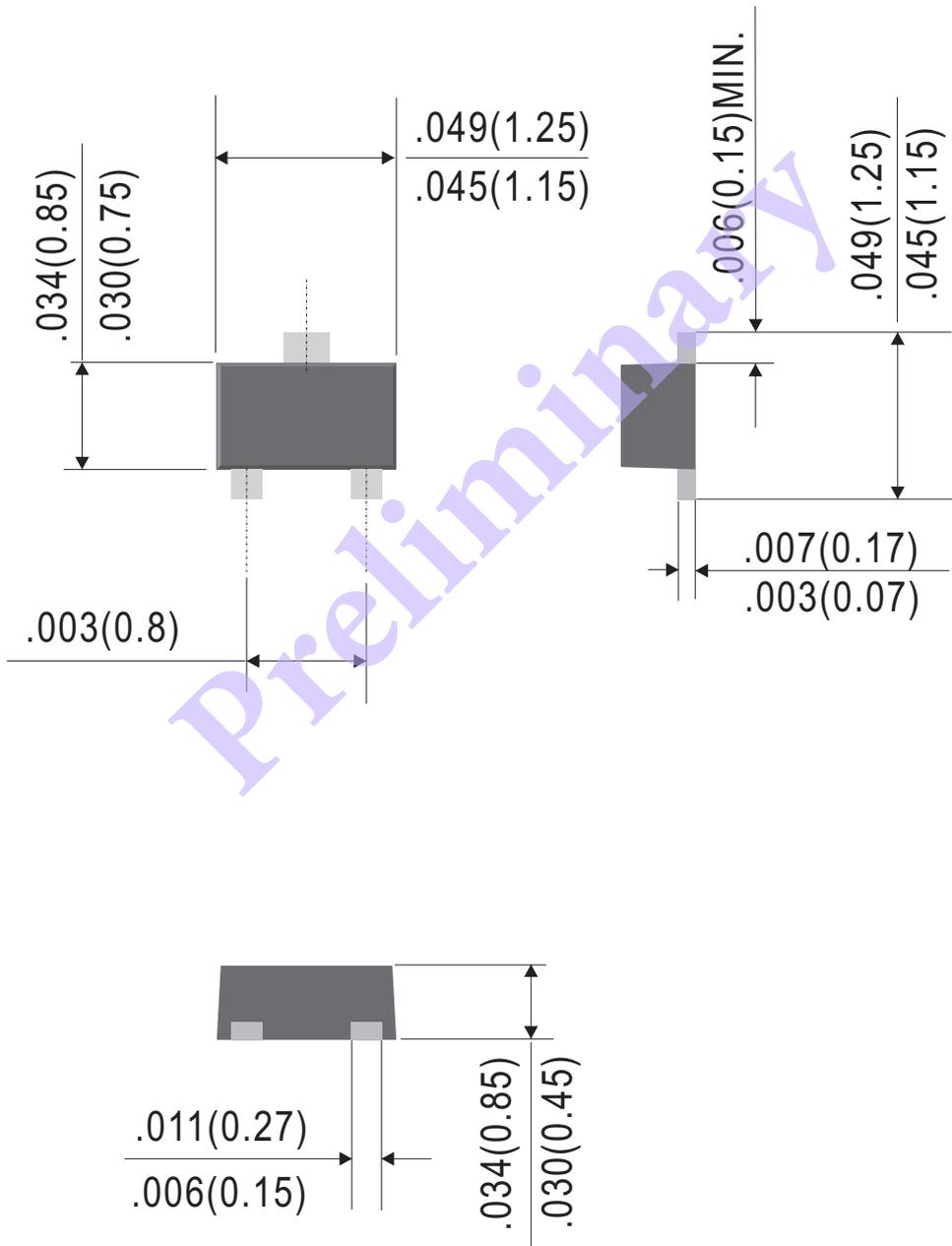
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	V _(BR)	I _R =100uA	80			V
Reverse current	I _R	V _R =70V			0.1	μA
Forward voltage	V _F	I _F =100mA			1.2	V
Total capacitance	C _{tot}	V _R =6V,f=1MHz			3.5	pF
Reverse recovery time	t _{rr}	I _F = I _R =5mA, V _R =6V,R _L =50 Ω			4	ns



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Outline Drawing

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Dimensions in inches and (millimeters)